



INVENTOR: MARK SIMPSON ET AL

Attorney Docket: US 010610

Title: DUAL GATE OXIDE HIGH-VOLTAGE SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME

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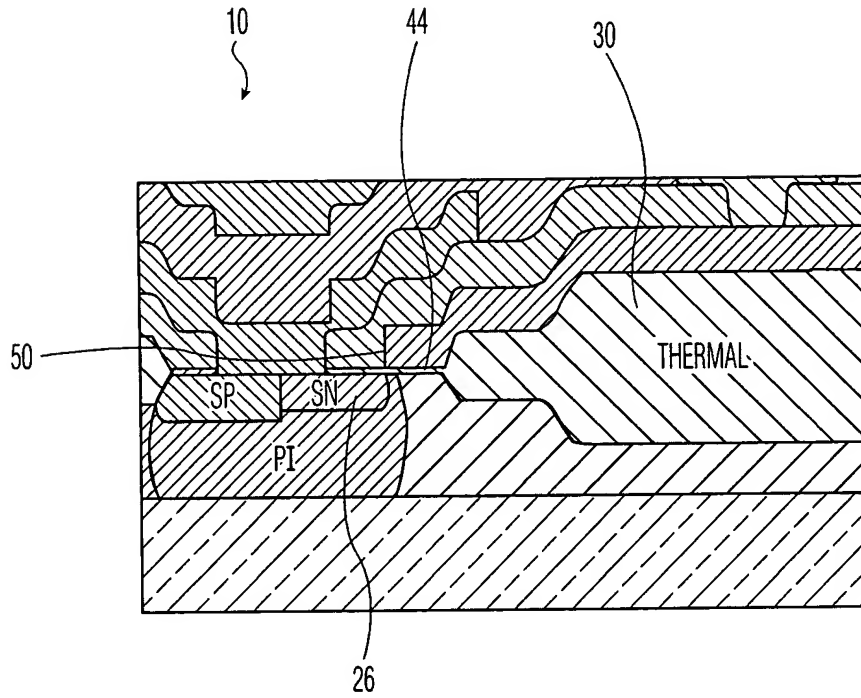


FIG. 2  
RELATED ART

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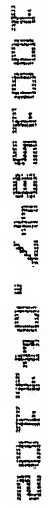


FIG. 3